

Thyristor Diode Modules

TYPE: YZPST-SKKH72/16E

Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Precious metal pressure contacts for high reliability
- Thyristor with amplifying gate

Typical Applications

- DC motor control
- Temperature control
- Professional light dimming

Maximum Ratings

Symbol	Condition	Ratings	Unit
$I_{T(AV)}$	Single phase, half wave, sin 180° conduction ; $T_C=85^{\circ}C$	70	A
I_{TRMS}	Single phase, half wave, sin 180° conduction	125	A
I_{TSM}	$T_j = T_{j\ MAX}$	1.45	kA
I^2t	$T_j = T_{j\ MAX}$	10.5	kA^2S
V_{DRM}/V_{RRM}	$T_j = T_{j\ MAX}$	1600/1600	V
di/dt	non-repetitive	150	A/us
V_{iso}	A.C.1minute/1S	4000/4800	V
T_j		-40 ~ + 125	$^{\circ}C$
T_{stg}		-40 ~ + 125	$^{\circ}C$
W	About	95	g

Electrical Characteristics

Symbol	Condition	Ratings	Unit
I_{DRM} / I_{RRM}	At V_{DRM} , Single phase, half wave, $T_j = T_{j\ MAX}$	30	mA
V_{TM}	On-State Current 300A, $T_j = 25^{\circ}C$	1.9	V
$V_{T(TO)}$	$T_j = T_{j\ MAX}$	0.9	V
r_T	$T_j = T_{j\ MAX}$	3.5	m Ω
R_{K1G1}		-	Ω
R_{K2G2}		-	Ω
t_{gd}	$T_j = 25^{\circ}C$; $V_D = 0.4V_{DRM}$; $I_{TM} = I_{TAV}$	1	us
t_q	$dv_D/dt = 50V/us$; $T_j = T_{j\ MAX}$; $I_{TM} = I_{TAV}$	80	us
I_{GT}/V_{GT}	$T_j = 25^{\circ}C$, $I_T = 1A$, $V_D = 6V$	150 / 3.0	mA/V
V_{GD}	$V_D = 67\%V_{DRM}$	0.25	V
DV/DT	$V_D = 67\%V_{DRM}$	1000	V/us
I_H	$T_j = 25^{\circ}C$	250	mA
I_L	$T_j = 25^{\circ}C$	600	mA
$R_{th(j-c)}$	Thermal resistance Junction to case; per module	0.35	K/W
$R_{th(c-h)}$	Thermal resistance case to heatsink; per module	0.2	K/W

Outline Drawing

